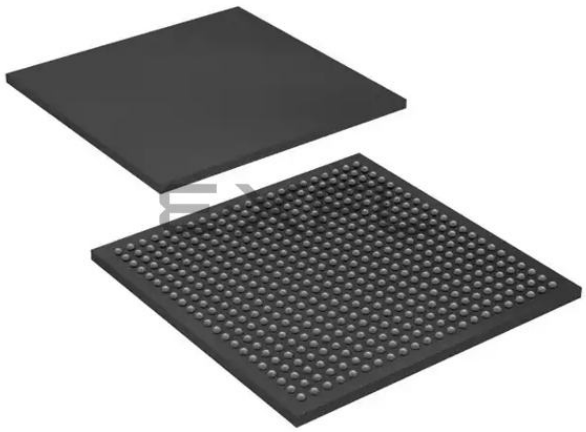

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Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	3022
Number of Logic Elements/Cells	60440
Total RAM Bits	2544192
Number of I/O	334
Number of Gates	-
Voltage - Supply	1.15V ~ 1.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	484-BBGA
Supplier Device Package	484-FBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/intel/ep2s60f484c4

Stratix II devices are available in space-saving FineLine BGA® packages (see Tables 1–2 and 1–3).

Table 1–2. Stratix II Package Options & I/O Pin Counts *Notes (1), (2)*

Device	484-Pin FineLine BGA	484-Pin Hybrid FineLine BGA	672-Pin FineLine BGA	780-Pin FineLine BGA	1,020-Pin FineLine BGA	1,508-Pin FineLine BGA
EP2S15	342		366			
EP2S30	342		500			
EP2S60 *(3)*	334		492		718	
EP2S90 *(3)*		308		534	758	902
EP2S130 *(3)*				534	742	1,126
EP2S180 *(3)*					742	1,170

Notes to Table 1–2:

(1) All I/O pin counts include eight dedicated clock input pins (`clk1p`, `clk1n`, `clk3p`, `clk3n`, `clk9p`, `clk9n`, `clk11p`, and `clk11n`) that can be used for data inputs.

(2) The Quartus II software I/O pin counts include one additional pin, `PLL_ENA`, which is not available as general-purpose I/O pins. The `PLL_ENA` pin can only be used to enable the PLLs within the device.

(3) The I/O pin counts for the EP2S60, EP2S90, EP2S130, and EP2S180 devices in the 1020-pin and 1508-pin packages include eight dedicated fast PLL clock inputs (`FPLL7CLKp/n`, `FPLL8CLKp/n`, `FPLL9CLKp/n`, and `FPLL10CLKp/n`) that can be used for data inputs.

Table 1–3. Stratix II FineLine BGA Package Sizes

Dimension	484 Pin	484-Pin Hybrid	672 Pin	780 Pin	1,020 Pin	1,508 Pin
Pitch (mm)	1.00	1.00	1.00	1.00	1.00	1.00
Area (mm2)	529	729	729	841	1,089	1,600
Length × width (mm × mm)	23 × 23	27 × 27	27 × 27	29 × 29	33 × 33	40 × 40

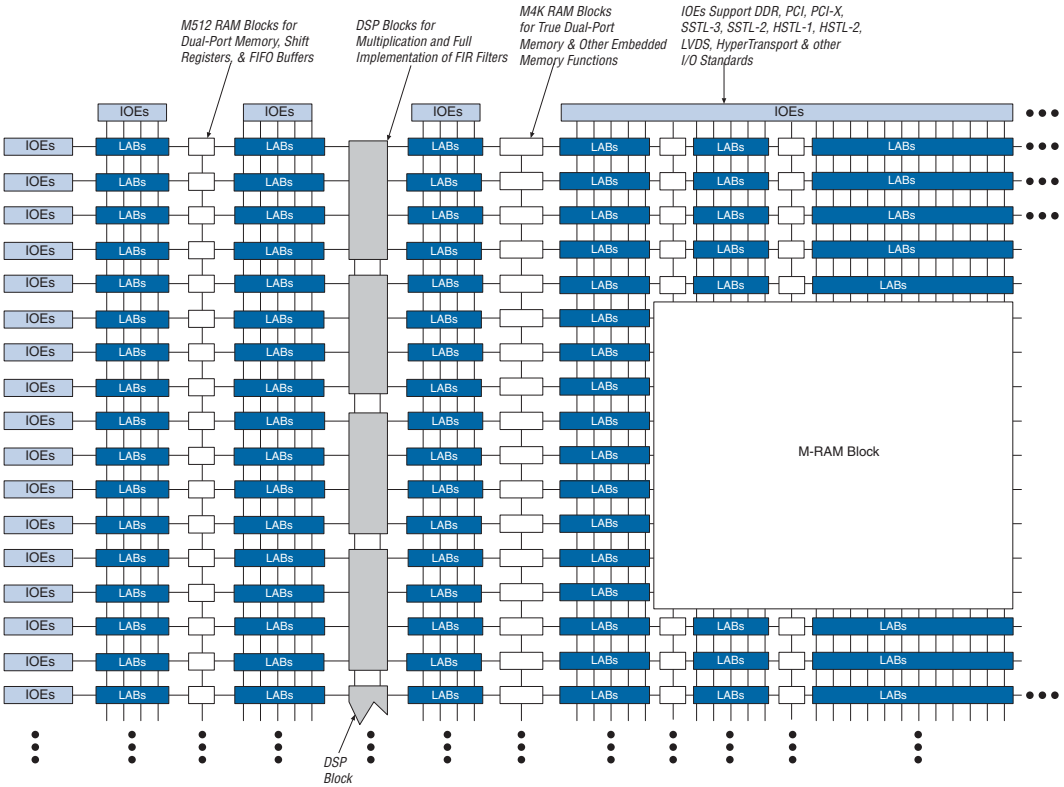
All Stratix II devices support vertical migration within the same package (for example, you can migrate between the EP2S15, EP2S30, and EP2S60 devices in the 672-pin FineLine BGA package). Vertical migration means that you can migrate to devices whose dedicated pins, configuration pins, and power pins are the same for a given package across device densities.

To ensure that a board layout supports migratable densities within one package offering, enable the applicable vertical migration path within the Quartus II software (Assignments menu > Device > Migration Devices).

Each Stratix II device I/O pin is fed by an I/O element (IOE) located at the end of LAB rows and columns around the periphery of the device. I/O pins support numerous single-ended and differential I/O standards. Each IOE contains a bidirectional I/O buffer and six registers for registering input, output, and output-enable signals. When used with dedicated clocks, these registers provide exceptional performance and interface support with external memory devices such as DDR and DDR2 SDRAM, RLDRAM II, and QDR II SRAM devices. High-speed serial interface channels with dynamic phase alignment (DPA) support data transfer at up to 1 Gbps using LVDS or HyperTransport™ technology I/O standards.

Figure 2–1 shows an overview of the Stratix II device.

Figure 2–1. Stratix II Block Diagram



completely backward-compatible with four-input LUT architectures. One ALM can also implement any function of up to six inputs and certain seven-input functions.

In addition to the adaptive LUT-based resources, each ALM contains two programmable registers, two dedicated full adders, a carry chain, a shared arithmetic chain, and a register chain. Through these dedicated resources, the ALM can efficiently implement various arithmetic functions and shift registers. Each ALM drives all types of interconnects: local, row, column, carry chain, shared arithmetic chain, register chain, and direct link interconnects. Figure 2–5 shows a high-level block diagram of the Stratix II ALM while Figure 2–6 shows a detailed view of all the connections in the ALM.

Figure 2–5. High-Level Block Diagram of the Stratix II ALM

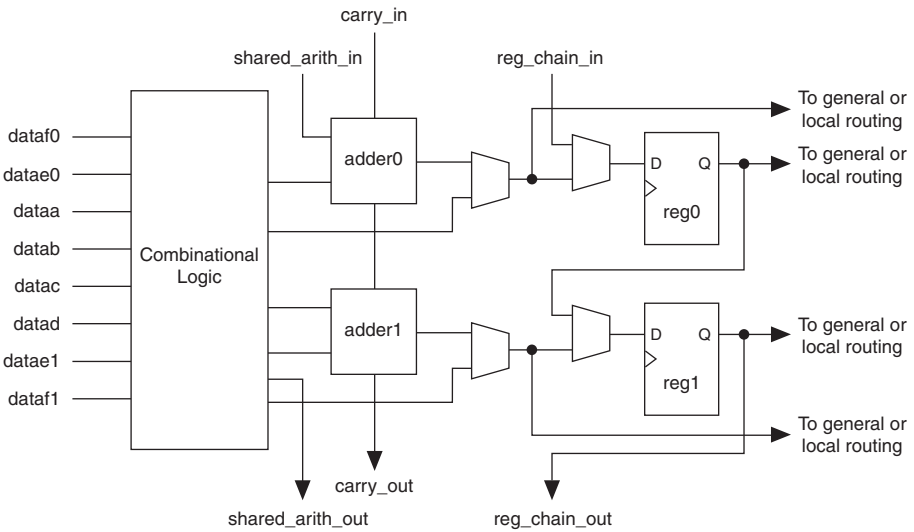
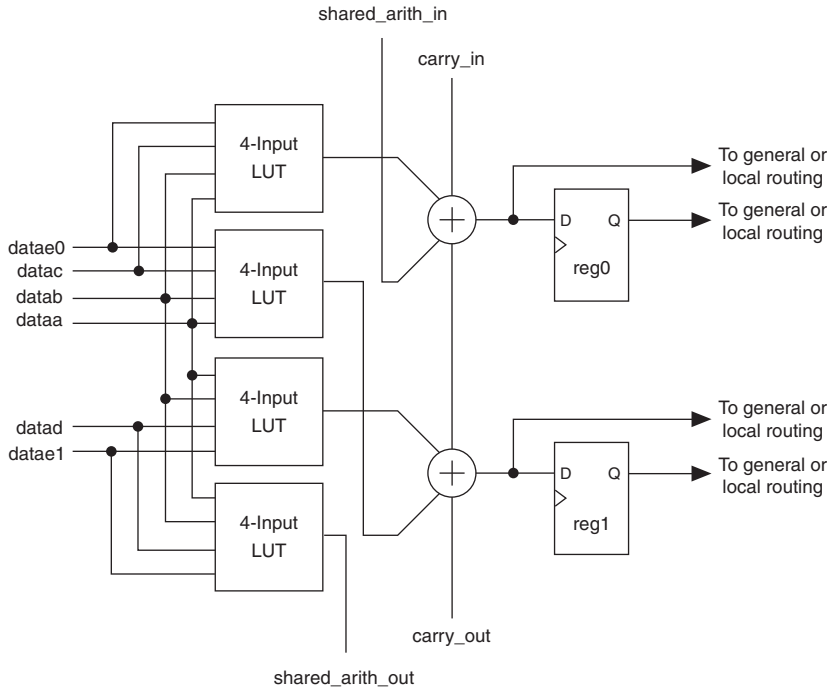


Figure 2–13. ALM in Shared Arithmetic Mode



Note to Figure 2–13:
(1) Inputs `dataf0` and `dataf1` are available for register packing in shared arithmetic mode.

Adder trees can be found in many different applications. For example, the summation of the partial products in a logic-based multiplier can be implemented in a tree structure. Another example is a correlator function that can use a large adder tree to sum filtered data samples in a given time frame to recover or to de-spread data which was transmitted utilizing spread spectrum technology.

An example of a three-bit add operation utilizing the shared arithmetic mode is shown in Figure 2–14. The partial sum `(S[2..0])` and the partial carry `(C[2..0])` is obtained using the LUTs, while the result `(R[2..0])` is computed using the dedicated adders.

arithmetic chain runs vertically allowing fast horizontal connections to TriMatrix memory and DSP blocks. A shared arithmetic chain can continue as far as a full column.

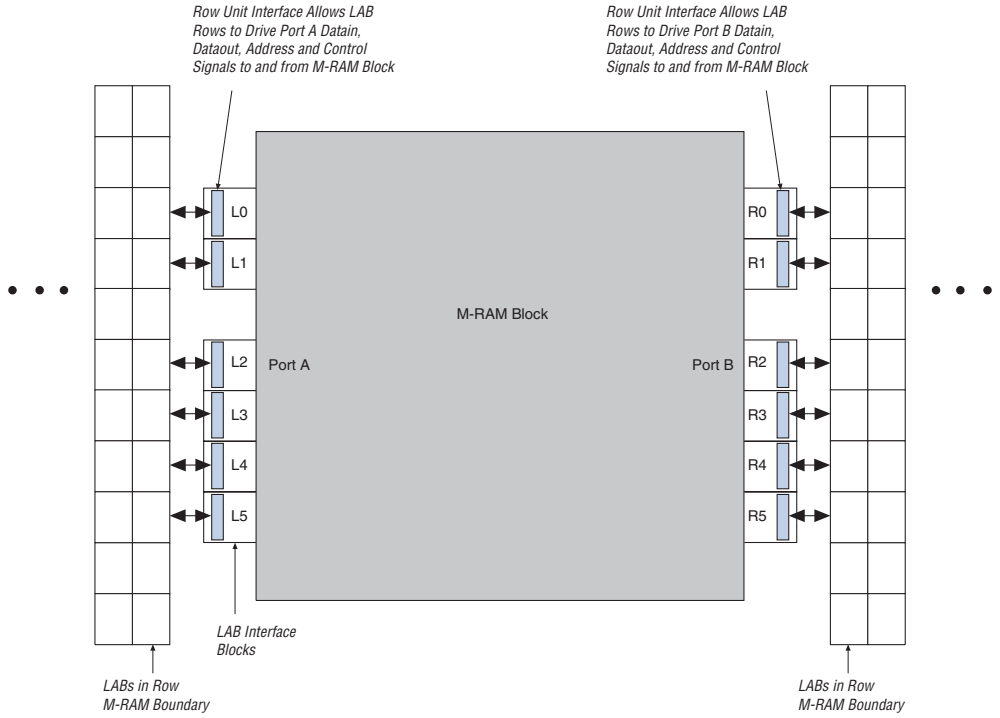
Similar to the carry chains, the shared arithmetic chains are also top- or bottom-half bypassable. This capability allows the shared arithmetic chain to cascade through half of the ALMs in a LAB while leaving the other half available for narrower fan-in functionality. Every other LAB column is top-half bypassable, while the other LAB columns are bottom-half bypassable.

See the "MultiTrack Interconnect" on page 2–22 section for more information on shared arithmetic chain interconnect.

Register Chain

In addition to the general routing outputs, the ALMs in an LAB have register chain outputs. The register chain routing allows registers in the same LAB to be cascaded together. The register chain interconnect allows an LAB to use LUTs for a single combinational function and the registers to be used for an unrelated shift register implementation. These resources speed up connections between ALMs while saving local interconnect resources (see Figure 2–15). The Quartus II Compiler automatically takes advantage of these resources to improve utilization and performance.

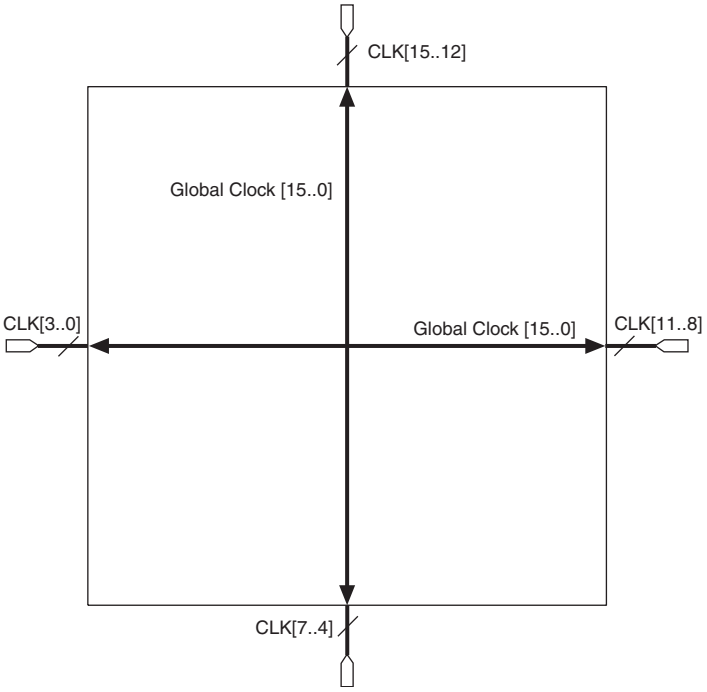
Figure 2–25. M-RAM Block LAB Row Interface *Note (1)*



Note to Figure 2–25:
(1) Only R24 and C16 interconnects cross the M-RAM block boundaries.

global clock networks can also be driven by internal logic for internally generated global clocks and asynchronous clears, clock enables, or other control signals with large fanout. Figure 2–31 shows the 16 dedicated CLK pins driving global clock networks.

Figure 2–31. Global Clocking



Regional Clock Network

There are eight regional clock networks RCLK[7..0] in each quadrant of the Stratix II device that are driven by the dedicated CLK[15..0] input pins, by PLL outputs, or by internal logic. The regional clock networks provide the lowest clock delay and skew for logic contained in a single quadrant. The CLK clock pins symmetrically drive the RCLK networks in a particular quadrant, as shown in Figure 2–32.

Table 2–11. Global & Regional Clock Connections from Top Clock Pins & Enhanced PLL Outputs (Part 2 of 2)

Top Side Global & Regional Clock Network Connectivity	DLLCLK	CLK12	CLK13	CLK14	CLK15	RCLK24	RCLK25	RCLK26	RCLK27	RCLK28	RCLK29	RCLK30	RCLK31
c4	✓					✓		✓		✓		✓	
c5	✓						✓		✓		✓		✓
Enhanced PLL 11 outputs													
c0		✓	✓			✓				✓			
c1		✓	✓				✓				✓		
c2				✓	✓			✓				✓	
c3				✓	✓				✓				✓
c4						✓		✓		✓		✓	
c5							✓		✓		✓		✓

Table 2–12. Global & Regional Clock Connections from Bottom Clock Pins & Enhanced PLL Outputs (Part 1 of 2)

Bottom Side Global & Regional Clock Network Connectivity	DLLCLK	CLK4	CLK5	CLK6	CLK7	RCLK8	RCLK9	RCLK10	RCLK11	RCLK12	RCLK13	RCLK14	RCLK15
Clock pins													
CLK4p	✓	✓	✓			✓				✓			
CLK5p	✓	✓	✓				✓				✓		
CLK6p	✓			✓	✓			✓				✓	
CLK7p	✓			✓	✓				✓				✓
CLK4n		✓				✓				✓			
CLK5n			✓				✓				✓		
CLK6n				✓				✓				✓	
CLK7n					✓				✓				✓
Drivers from internal logic													
GCLKDRV0		✓											
GCLKDRV1			✓										
GCLKDRV2				✓									

Table 2–12. Global & Regional Clock Connections from Bottom Clock Pins & Enhanced PLL Outputs (Part 2 of 2)

Bottom Side Global & Regional Clock Network Connectivity	DLLCLK	CLK4	CLK5	CLK6	CLK7	RCLK8	RCLK9	RCLK10	RCLK11	RCLK12	RCLK13	RCLK14	RCLK15
GCLKDRV3					✓								
RCLKDRV0						✓				✓			
RCLKDRV1							✓				✓		
RCLKDRV2								✓				✓	
RCLKDRV3									✓				✓
RCLKDRV4						✓				✓			
RCLKDRV5							✓				✓		
RCLKDRV6								✓				✓	
RCLKDRV7									✓				✓
Enhanced PLL 6 outputs													
c0	✓	✓	✓			✓				✓			
c1	✓	✓	✓				✓				✓		
c2	✓			✓	✓			✓				✓	
c3	✓			✓	✓				✓				✓
c4	✓					✓		✓		✓		✓	
c5	✓						✓		✓		✓		✓
Enhanced PLL 12 outputs													
c0		✓	✓			✓				✓			
c1		✓	✓				✓				✓		
c2				✓	✓			✓				✓	
c3				✓	✓				✓				✓
c4						✓		✓		✓		✓	
c5							✓		✓		✓		✓

Each I/O bank has its own VCCIO pins. A single device can support 1.5-, 1.8-, 2.5-, and 3.3-V interfaces; each bank can support a different V_{CCIO} level independently. Each bank also has dedicated VREF pins to support the voltage-referenced standards (such as SSTL-2). The PLL banks utilize the adjacent VREF group when voltage-referenced standards are implemented. For example, if an SSTL input is implemented in PLL bank 10, the voltage level at VREFB7 is the reference voltage level for the SSTL input.

I/O pins that reside in PLL banks 9 through 12 are powered by the VCC_PLL<*5, 6, 11, or 12*>_OUT pins, respectively. The EP2S60F484, EP2S60F780, EP2S90H484, EP2S90F780, and EP2S130F780 devices do not support PLLs 11 and 12. Therefore, any I/O pins that reside in bank 11 are powered by the VCCIO3 pin, and any I/O pins that reside in bank 12 are powered by the VCCIO8 pin.

Each I/O bank can support multiple standards with the same V_{CCIO} for input and output pins. Each bank can support one V_{REF} voltage level. For example, when V_{CCIO} is 3.3 V, a bank can support LVTTL, LVCMOS, and 3.3-V PCI for inputs and outputs.

On-Chip Termination

Stratix II devices provide differential (for the LVDS or HyperTransport technology I/O standard), series, and parallel on-chip termination to reduce reflections and maintain signal integrity. On-chip termination simplifies board design by minimizing the number of external termination resistors required. Termination can be placed inside the package, eliminating small stubs that can still lead to reflections.

Stratix II devices provide four types of termination:

- Differential termination (R_D)
- Series termination (R_S) without calibration
- Series termination (R_S) with calibration
- Parallel termination (R_T) with calibration

The PLL_ENA pin and the configuration input pins (Table 3–4) have a dual buffer design: a 3.3-V/2.5-V input buffer and a 1.8-V/1.5-V input buffer. The VCCSEL input pin selects which input buffer is used. The 3.3-V/2.5-V input buffer is powered by $V_{CCPD,}$ while the 1.8-V/1.5-V input buffer is powered by V_{CCIO}. Table 3–4 shows the pins affected by VCCSEL.

Table 3–4. Pins Affected by the Voltage Level at VCCSEL

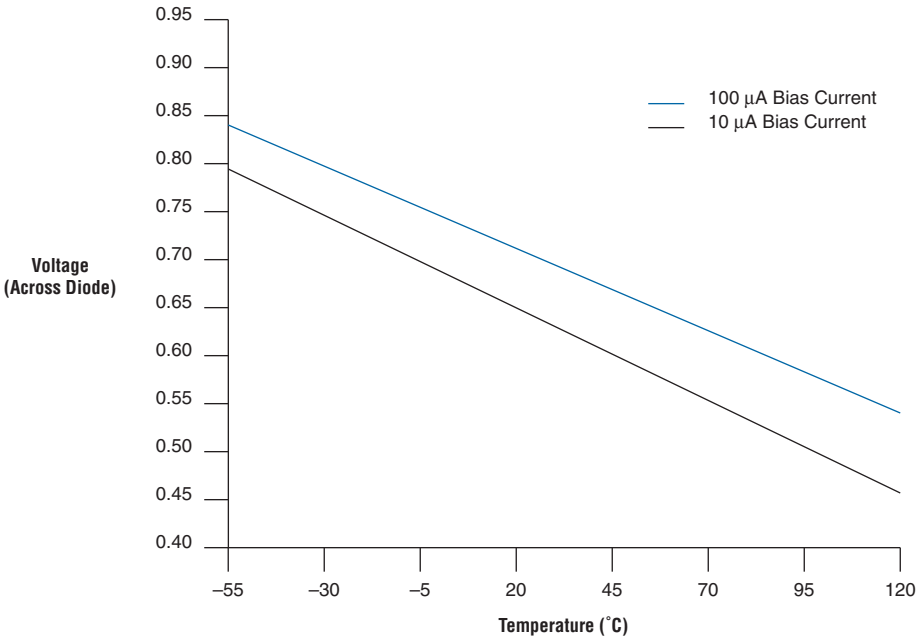
Pin	VCCSEL = LOW (connected to GND)	VCCSEL = HIGH (connected to V_{CCPD})
nSTATUS (when used as an input)	3.3/2.5-V input buffer is selected. Input buffer is powered by V_{CCPD}.	1.8/1.5-V input buffer is selected. Input buffer is powered by V_{CCIO} of the I/O bank.
nCONFIG		
CONF_DONE (when used as an input)		
DATA[7..0]		
nCE		
DCLK (when used as an input)		
CS		
nWS		
nRS		
nCS		
CLKUSR		
DEV_OE		
DEV_CLRn		
RUnLU		
PLL_ENA		

VCCSEL is sampled during power-up. Therefore, the VCCSEL setting cannot change on the fly or during a reconfiguration. The VCCSEL input buffer is powered by V_{CCINT} and must be hardwired to V_{CCPD} or ground. A logic high VCCSEL connection selects the 1.8-V/1.5-V input buffer, and a logic low selects the 3.3-V/2.5-V input buffer. VCCSEL should be set to comply with the logic levels driven out of the configuration device or MAX® II/microprocessor.

If you need to support configuration input voltages of 3.3 V/2.5 V, you should set the VCCSEL to a logic low; you can set the V_{CCIO} of the I/O bank that contains the configuration inputs to any supported voltage. If

The temperature-sensing diode works for the entire operating range, as shown in Figure 3–2.

Figure 3–2. Temperature vs. Temperature-Sensing Diode Voltage



The temperature sensing diode is a very sensitive circuit which can be influenced by noise coupled from other traces on the board, and possibly within the device package itself, depending on device usage. The interfacing device registers temperature based on milivolts of difference as seen at the TSD. Switching I/O near the TSD pins can affect the temperature reading. Altera recommends you take temperature readings during periods of no activity in the device (for example, standby mode where no clocks are toggling in the device), such as when the nearby I/Os are at a DC state, and disable clock networks in the device.

Automated Single Event Upset (SEU) Detection

Stratix II devices offer on-chip circuitry for automated checking of single event upset (SEU) detection. Some applications that require the device to operate error free at high elevations or in close proximity to Earth's North or South Pole require periodic checks to ensure continued data integrity. The error detection cyclic redundancy check (CRC) feature controlled by

Table 5–2. Maximum Duty Cycles in Voltage Transitions				
Symbol	**Parameter**	**Condition**	**Maximum Duty Cycles**	**Unit**
V_I	Maximum duty cycles in voltage transitions	V_I = 4.0 V	100	%
		V_I = 4.1 V	90	%
		V_I = 4.2 V	50	%
		V_I = 4.3 V	30	%
		V_I = 4.4 V	17	%
		V_I = 4.5 V	10	%

Recommended Operating Conditions

Table 5–3 contains the Stratix II device family recommended operating conditions.

Table 5–3. Stratix II Device Recommended Operating Conditions (Part 1 of 2) Note (1)					
Symbol	**Parameter**	**Conditions**	**Minimum**	**Maximum**	**Unit**
V_{CCINT}	Supply voltage for internal logic	100 µs ≤ risetime ≤ 100 ms *(3)*	1.15	1.25	V
V_{CCIO}	Supply voltage for input and output buffers, 3.3-V operation	100 µs ≤ risetime ≤ 100 ms *(3)*, *(6)*	3.135 (3.00)	3.465 (3.60)	V
	Supply voltage for input and output buffers, 2.5-V operation	100 µs ≤ risetime ≤ 100 ms *(3)*	2.375	2.625	V
	Supply voltage for input and output buffers, 1.8-V operation	100 µs ≤ risetime ≤ 100 ms *(3)*	1.71	1.89	V
	Supply voltage for output buffers, 1.5-V operation	100 µs ≤ risetime ≤ 100 ms *(3)*	1.425	1.575	V
	Supply voltage for input and output buffers, 1.2-V operation	100 µs ≤ risetime ≤ 100 ms *(3)*	1.14	1.26	V
V_{CCPD}	Supply voltage for pre-drivers as well as configuration and JTAG I/O buffers.	100 µs ≤ risetime ≤ 100 ms *(4)*	3.135	3.465	V
V_{CCA}	Analog power supply for PLLs	100 µs ≤ risetime ≤ 100 ms *(3)*	1.15	1.25	V
V_{CCD}	Digital power supply for PLLs	100 µs ≤ risetime ≤ 100 ms *(3)*	1.15	1.25	V
V_I	Input voltage (see Table 5–2)	*(2)*, *(5)*	–0.5	4.0	V
V_O	Output voltage		0	V_{CCIO}	V

Table 5–3. Stratix II Device Recommended Operating Conditions (Part 2 of 2) Note (1)					
Symbol	**Parameter**	**Conditions**	**Minimum**	**Maximum**	**Unit**
T_J	Operating junction temperature	For commercial use	0	85	°C
		For industrial use	–40	100	°C
		For military use *(7)*	–55	125	°C

Notes to Table 5–3:

(1) Supply voltage specifications apply to voltage readings taken at the device pins, not at the power supply.

(2) During transitions, the inputs may overshoot to the voltage shown in Table 5–2 based upon the input duty cycle. The DC case is equivalent to 100% duty cycle. During transitions, the inputs may undershoot to –2.0 V for input currents less than 100 mA and periods shorter than 20 ns.

(3) Maximum V_{CC} rise time is 100 ms, and V_{CC} must rise monotonically from ground to V_{CC}.

(4) V_{CCPD} must ramp-up from 0 V to 3.3 V within 100 µs to 100 ms. If V_{CCPD} is not ramped up within this specified time, your Stratix II device does not configure successfully. If your system does not allow for a V_{CCPD} ramp-up time of 100 ms or less, you must hold `nCONFIG` low until all power supplies are reliable.

(5) All pins, including dedicated inputs, clock, I/O, and JTAG pins, may be driven before V_{CCINT}, V_{CCPD}, and V_{CCIO} are powered.

(6) V_{CCIO} maximum and minimum conditions for PCI and PCI-X are shown in parentheses.

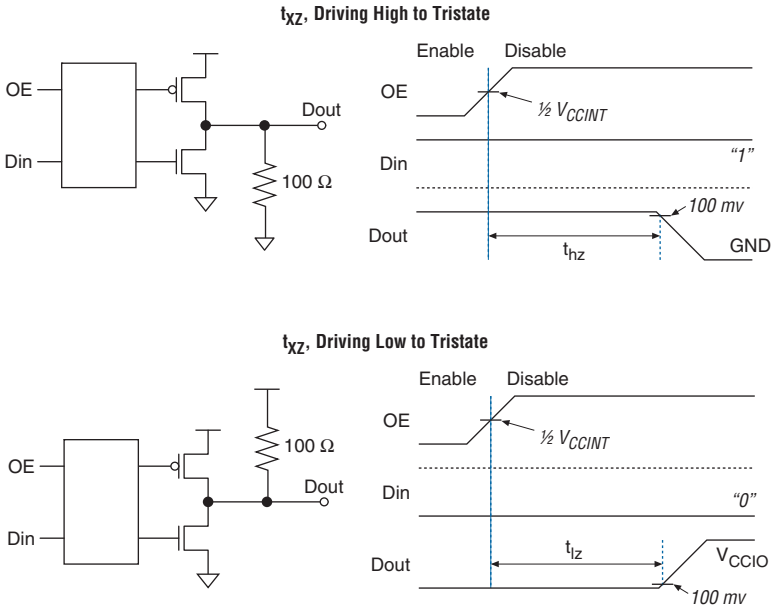
(7) For more information, refer to the *Stratix II Military Temperature Range Support* technical brief.

DC Electrical Characteristics

Table 5–4 shows the Stratix II device family DC electrical characteristics.

Table 5–4. Stratix II Device DC Operating Conditions (Part 1 of 2) Note (1)							
Symbol	**Parameter**	**Conditions**		**Minimum**	**Typical**	**Maximum**	**Unit**
I_I	Input pin leakage current	$V_I = V_{CCIOmax}$ to 0 V *(2)*		–10		10	µA
I_{OZ}	Tri-stated I/O pin leakage current	$V_O = V_{CCIOmax}$ to 0 V *(2)*		–10		10	µA
I_{CCINT0}	V_{CCINT} supply current (standby)	V_I = ground, no load, no toggling inputs T_J = 25° C	EP2S15		0.25	*(3)*	A
			EP2S30		0.30	*(3)*	A
			EP2S60		0.50	*(3)*	A
			EP2S90		0.62	*(3)*	A
			EP2S130		0.82	*(3)*	A
			EP2S180		1.12	*(3)*	A
I_{CCPD0}	V_{CCPD} supply current (standby)	V_I = ground, no load, no toggling inputs T_J = 25° C, V_{CCPD} = 3.3V	EP2S15		2.2	*(3)*	mA
			EP2S30		2.7	*(3)*	mA
			EP2S60		3.6	*(3)*	mA
			EP2S90		4.3	*(3)*	mA
			EP2S130		5.4	*(3)*	mA
			EP2S180		6.8	*(3)*	mA

Figure 5–5. Measurement Setup for t_{xz} *Note (1)*



Note to Figure 5–5:
(1) V_{CCINT} is 1.12 V for this measurement.

Table 5–36. Stratix II Performance Notes (Part 6 of 6) Note (1)

Applications		Resources Used			Performance				
		ALUTs	TriMatrix Memory Blocks	DSP Blocks	-3 Speed Grade (2)	-3 Speed Grade (3)	-4 Speed Grade	-5 Speed Grade	Unit
Larger designs	8-bit, 1024-point, quadrant output, four parallel FFT engines, buffered burst, three multipliers five adders FFT function	7385	60	36	359.58	352.98	312.01	278.00	MHz
	8-bit, 1024-point, quadrant output, four parallel FFT engines, buffered burst, four multipliers and two adders FFT function	6601	60	48	371.88	355.74	327.86	277.62	MHz

Notes for Table 5–36:

(1) These design performance numbers were obtained using the Quartus II software version 5.0 SP1.
(2) These numbers apply to -3 speed grade EP2S15, EP2S30, EP2S60, and EP2S90 devices.
(3) These numbers apply to -3 speed grade EP2S130 and EP2S180 devices.
(4) This application uses registered inputs and outputs.
(5) This application uses registered multiplier input and output stages within the DSP block.
(6) This application uses registered multiplier input, pipeline, and output stages within the DSP block.
(7) This application uses registered multiplier input with output of the multiplier stage feeding the accumulator or subtractor within the DSP block.
(8) This application uses the same clock source that is globally routed and connected to ports A and B.
(9) This application uses locally routed clocks or differently sourced clocks for ports A and B.

Table 5–78. Maximum Output Toggle Rate on Stratix II Devices (Part 4 of 5) *Note (1)*

I/O Standard	Drive Strength	Column I/O Pins (MHz)			Row I/O Pins (MHz)			Clock Outputs (MHz)		
		-3	-4	-5	-3	-4	-5	-3	-4	-5
1.8-V LVTTL	OCT 50 Ω	700	550	450	700	550	450	700	550	450
3.3-V LVCMOS	OCT 50 Ω	350	350	300	350	350	300	350	350	300
1.5-V LVCMOS	OCT 50 Ω	550	450	400	550	450	400	550	450	400
SSTL-2 Class I	OCT 50 Ω	600	500	500	600	500	500	600	500	500
SSTL-2 Class II	OCT 25 Ω	600	550	500	600	550	500	600	550	500
SSTL-18 Class I	OCT 50 Ω	560	400	350	590	400	350	450	400	350
SSTL-18 Class II	OCT 25 Ω	550	500	450	-	-	-	550	500	450
1.2-V HSTL *(2)*	OCT 50 Ω	280	-	-	-	-	-	280	-	-
1.5-V HSTL Class I	OCT 50 Ω	600	550	500	600	550	500	600	550	500
1.8-V HSTL Class I	OCT 50 Ω	650	600	600	650	600	600	650	600	600
1.8-V HSTL Class II	OCT 25 Ω	500	500	450	-	-	-	500	500	450
Differential SSTL-2 Class I	OCT 50 Ω	600	500	500	600	500	500	600	500	500
Differential SSTL-2 Class II	OCT 25 Ω	600	550	500	600	550	500	600	550	500
Differential SSTL-18 Class I	OCT 50 Ω	560	400	350	590	400	350	560	400	350
Differential SSTL-18 Class II	OCT 25 Ω	550	500	450	-	-	-	550	500	450
1.8-V Differential HSTL Class I	OCT 50 Ω	650	600	600	650	600	600	650	600	600
1.8-V Differential HSTL Class II	OCT 25 Ω	500	500	450	-	-	-	500	500	450
1.5-V Differential HSTL Class I	OCT 50 Ω	600	550	500	600	550	500	600	550	500

Table 5–79. Maximum Output Clock Toggle Rate Derating Factors (Part 2 of 5)

I/O Standard	Drive Strength	Maximum Output Clock Toggle Rate Derating Factors (ps/pF)								
		Column I/O Pins			Row I/O Pins			Dedicated Clock Outputs		
		-3	-4	-5	-3	-4	-5	-3	-4	-5
1.8-V LVTTL/LVCMOS	2 mA	951	1421	1421	951	1421	1421	904	1421	1421
	4 mA	405	516	516	405	516	516	393	516	516
	6 mA	261	325	325	261	325	325	253	325	325
	8 mA	223	274	274	223	274	274	224	274	274
	10 mA	194	236	236	-	-	-	199	236	236
	12 mA	174	209	209	-	-	-	180	209	209
1.5-V LVTTL/LVCMOS	2 mA	652	963	963	652	963	963	618	963	963
	4 mA	333	347	347	333	347	347	270	347	347
	6 mA	182	247	247	-	-	-	198	247	247
	8 mA	135	194	194	-	-	-	155	194	194
SSTL-2 Class I	8 mA	364	680	680	364	680	680	350	680	680
	12 mA	163	207	207	163	207	207	188	207	207
SSTL-2 Class II	16 mA	118	147	147	118	147	147	94	147	147
	20 mA	99	122	122	-	-	-	87	122	122
	24 mA	91	116	116	-	-	-	85	116	116
SSTL-18 Class I	4 mA	458	570	570	458	570	570	505	570	570
	6 mA	305	380	380	305	380	380	336	380	380
	8 mA	225	282	282	225	282	282	248	282	282
	10 mA	167	220	220	167	220	220	190	220	220
	12 mA	129	175	175	-	-	-	148	175	175
SSTL-18 Class II	8 mA	173	206	206	-	-	-	155	206	206
	16 mA	150	160	160	-	-	-	140	160	160
	18 mA	120	130	130	-	-	-	110	130	130
	20 mA	109	127	127	-	-	-	94	127	127
SSTL-2 Class I	8 mA	364	680	680	364	680	680	350	680	680
	12 mA	163	207	207	163	207	207	188	207	207
SSTL-2 Class II	16 mA	118	147	147	118	147	147	94	147	147
	20 mA	99	122	122	-	-	-	87	122	122
	24 mA	91	116	116	-	-	-	85	116	116

Table 5–84. Maximum DCD for DDIO Output on Column I/O Pins Without PLL in the Clock Path for -3 Devices (Part 2 of 2) *Notes (1), (2)*

DDIO Column Output I/O Standard	Maximum DCD Based on I/O Standard of Input Feeding the DDIO Clock Port (No PLL in the Clock Path)					Unit
	TTL/CMOS		SSTL-2	SSTL/HSTL	1.2-V HSTL	
	3.3/2.5 V	1.8/1.5 V	2.5 V	1.8/1.5 V	1.2 V	
1.8 V	150	265	85	85	85	ps
1.5-V LVCMOS	255	370	140	140	140	ps
SSTL-2 Class I	175	295	65	65	65	ps
SSTL-2 Class II	170	290	60	60	60	ps
SSTL-18 Class I	155	275	55	50	50	ps
SSTL-18 Class II	140	260	70	70	70	ps
1.8-V HSTL Class I	150	270	60	60	60	ps
1.8-V HSTL Class II	150	270	60	60	60	ps
1.5-V HSTL Class I	150	270	55	55	55	ps
1.5-V HSTL Class II	125	240	85	85	85	ps
1.2-V HSTL	240	360	155	155	155	ps
LVPECL	180	180	180	180	180	ps

Notes to Table 5–84:
(1) Table 5–84 assumes the input clock has zero DCD.
(2) The DCD specification is based on a no logic array noise condition.

Table 5–85. Maximum DCD for DDIO Output on Column I/O Pins Without PLL in the Clock Path for -4 & -5 Devices (Part 1 of 2) *Notes (1), (2)*

DDIO Column Output I/O Standard	Maximum DCD Based on I/O Standard of Input Feeding the DDIO Clock Port (No PLL in the Clock Path)				Unit
	TTL/CMOS		SSTL-2	SSTL/HSTL	
	3.3/2.5 V	1.8/1.5 V	2.5 V	1.8/1.5 V	
3.3-V LVTTL	440	495	170	160	ps
3.3-V LVCMOS	390	450	120	110	ps
2.5 V	375	430	105	95	ps
1.8 V	325	385	90	100	ps
1.5-V LVCMOS	430	490	160	155	ps
SSTL-2 Class I	355	410	85	75	ps
SSTL-2 Class II	350	405	80	70	ps

Table 5–90 shows the high-speed I/O timing specifications for -4 speed grade Stratix II devices.

Table 5–90. High-Speed I/O Specifications for -4 Speed Grade *Notes (1), (2)*

Symbol	Conditions	-4 Speed Grade			Unit
		Min	Typ	Max	
f_{HSCLK} (clock frequency) $f_{HSCLK} = f_{HSDR} / W$	W = 2 to 32 (LVDS, HyperTransport technology) *(3)*	16		520	MHz
	W = 1 (SERDES bypass, LVDS only)	16		500	MHz
	W = 1 (SERDES used, LVDS only)	150		717	MHz
f_{HSDR} (data rate)	J = 4 to 10 (LVDS, HyperTransport technology)	150		1,040	Mbps
	J = 2 (LVDS, HyperTransport technology)	*(4)*		760	Mbps
	J = 1 (LVDS only)	*(4)*		500	Mbps
$f_{HSDRDPA}$ (DPA data rate)	J = 4 to 10 (LVDS, HyperTransport technology)	150		1,040	Mbps
TCCS	All differential standards	-		200	ps
SW	All differential standards	330		-	ps
Output jitter				190	ps
Output t_{RISE}	All differential I/O standards			160	ps
Output t_{FALL}	All differential I/O standards			180	ps
t_{DUTY}		45	50	55	%
DPA run length				6,400	UI
DPA jitter tolerance	Data channel peak-to-peak jitter	0.44			UI
DPA lock time	**Standard** / **Training Pattern** / **Transition Density**				Number of repetitions
	SPI-4 / 0000000000 1111111111 / 10%	256			
	Parallel Rapid I/O / 00001111 / 25%	256			
	Parallel Rapid I/O / 10010000 / 50%	256			
	Miscellaneous / 10101010 / 100%	256			
	Miscellaneous / 01010101 /	256			

Notes to Table 5–90:

(1) When J = 4 to 10, the SERDES block is used.

(2) When J = 1 or 2, the SERDES block is bypassed.

(3) The input clock frequency and the W factor must satisfy the following fast PLL VCO specification: 150 ≤ input clock frequency × W ≤ 1,040.

(4) The minimum specification is dependent on the clock source (fast PLL, enhanced PLL, clock pin, and so on) and the clock routing resource (global, regional, or local) utilized. The I/O differential buffer and input register do not have a minimum toggle rate.